

To our customers,

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## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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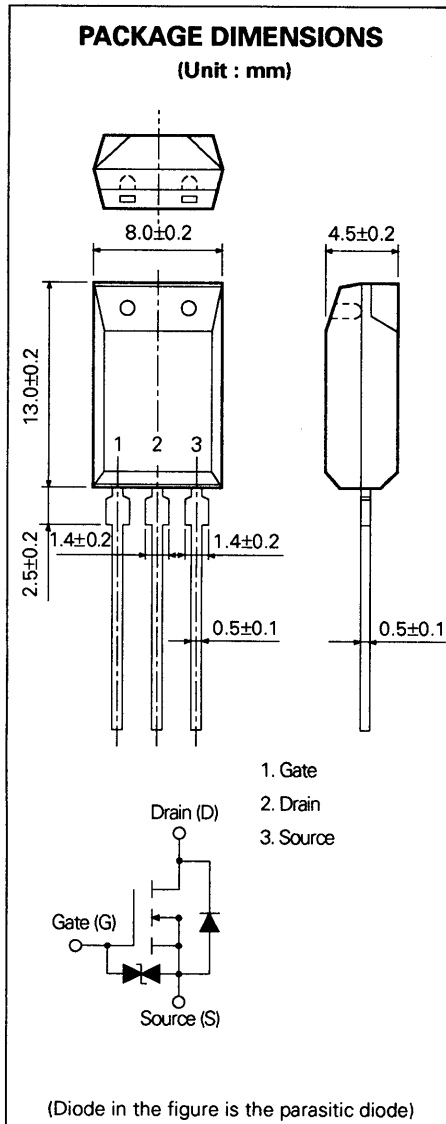
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SWITCHING  
N-CHANNEL POWER MOS FET  
INDUSTRIAL USE



**DESCRIPTION**

The 2SK2132 is N-channel Power MOS Field Effect Transistor designed for high voltage switching applications.

**FEATURES**

- Low On-state Resistance  
 $R_{DS(on)} = 0.65 \Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 2.0 \text{ A)}$
- Low  $C_{iss}$   $C_{iss} = 300 \text{ pF TYP.}$
- Built-in G-S Gate Protection Diodes
- High Avalanche Capability Ratings

**QUALITY GRADE**

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

**ABSOLUTE MAXIMUM RATINGS**

Maximum Temperatures

Storage Temperature	-55 to +150	°C
Channel Temperature	150	°C MAX.

Maximum Power Dissipation

Total Power Dissipation ( $T_a = 25 \text{ }^\circ\text{C}$ )	1.8	W
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Maximum Voltages and Currents ( $T_a = 25 \text{ }^\circ\text{C}$ )

$V_{DSS}$	Drain to Source Voltage	180	V
$V_{GSS}$	Gate to Source Voltage	$\pm 20$	V
$I_{D(DC)}$	Drain Current (DC)	$\pm 4.0$	A
$I_{D(pulse)^*}$	Drain Current (pulse)	$\pm 16$	A

Maximum Avalanche Capability Ratings\*\*

$I_{AS}$	Single Avalanche Current	4.0	A
EAS	Single Avalanche Energy	51.2	mJ

\*  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

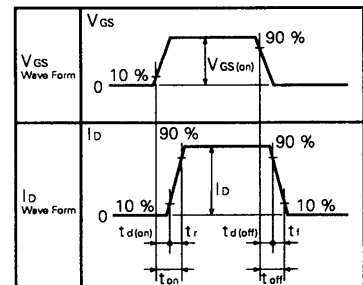
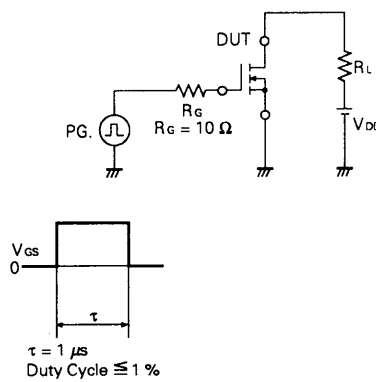
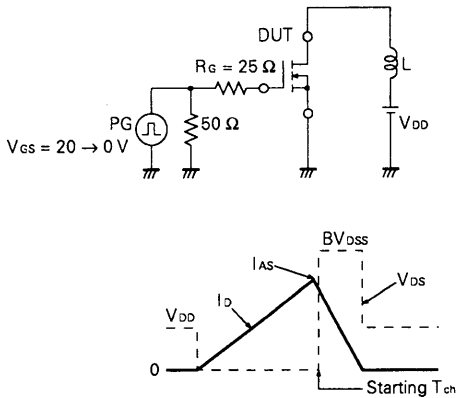
\*\* Starting  $T_{ch} = 25 \text{ }^\circ\text{C}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \text{ V} \rightarrow 0$

**ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)**

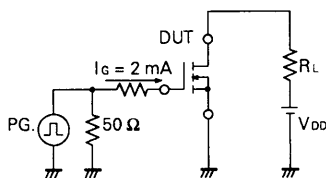
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	R <sub>DS (on)</sub>		0.52	0.65	Ω	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 18 A
Gate to Source Cutoff Voltage	V <sub>GS (off)</sub>	2.0		4.0	V	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA
Forward Transfer Admittance	y <sub>fs</sub>	0.5			S	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 18 A
Drain Leakage Current	I <sub>DSS</sub>			100	μA	V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0
Gate to Source Leakage Current	I <sub>GSS</sub>			±10	μA	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0
Input Capacitance	C <sub>iss</sub>		300		pF	V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0 f = 1 MHz
Output Capacitance	C <sub>oss</sub>		170		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>		50		pF	
Turn-On Delay Time	t <sub>d (on)</sub>		9.0		ns	V <sub>GS</sub> = 10 V V <sub>DD</sub> = 100 V I <sub>D</sub> = 2 A, R <sub>G</sub> = 10 Ω R <sub>L</sub> = 50 Ω
Rise Time	t <sub>r</sub>		10		ns	
Turn-Off Delay Time	t <sub>d (off)</sub>		28		ns	
Fall Time	t <sub>f</sub>		12		ns	
Total Gate Charge	Q <sub>G</sub>		10		nC	V <sub>GS</sub> = 10 V I <sub>D</sub> = 2 A V <sub>DD</sub> = 140 V
Gate to Source Charge	Q <sub>GS</sub>		2.3		nC	
Gate to Drain Charge	Q <sub>GD</sub>		4.7		nC	
Diode Forward Voltage	V <sub>F(S-D)</sub>		0.9		V	I <sub>F</sub> = 2 A, V <sub>GS</sub> = 0
Reverse Recovery Time	t <sub>rr</sub>		180		ns	I <sub>F</sub> = 2 A di / dt = 50 A/μs
Reverse Recovery Charge	Q <sub>rr</sub>		0.5		μC	

**Test Circuit 1 : Avalanche Capability**

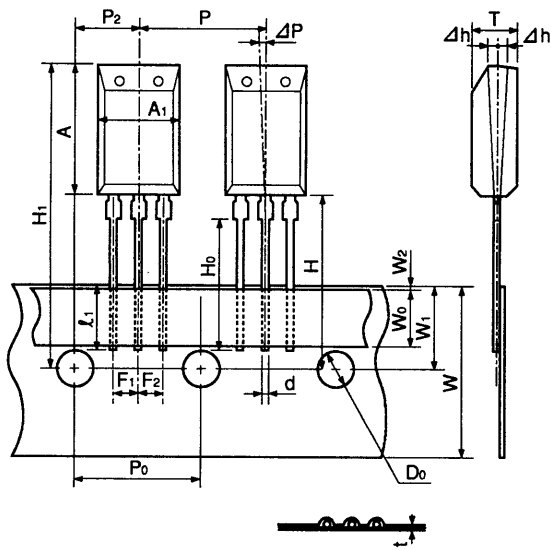
**Test Circuit 2 : Switching Time**



**Test Circuit 3 : Gate Charge**



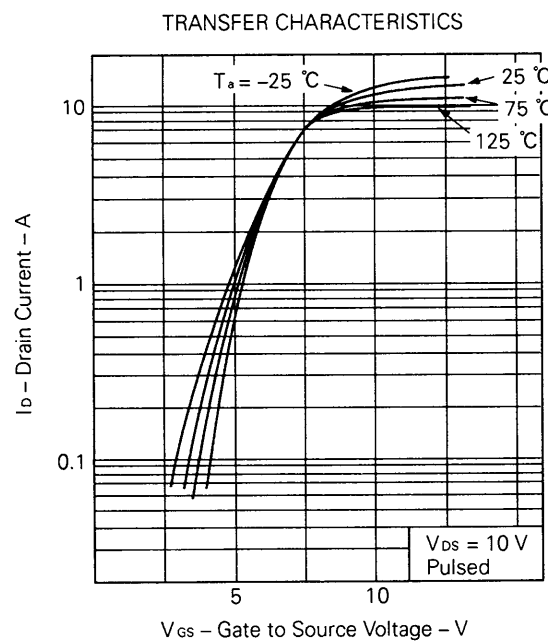
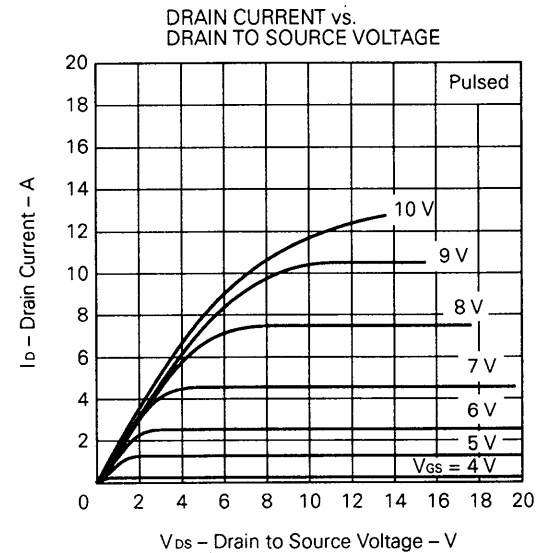
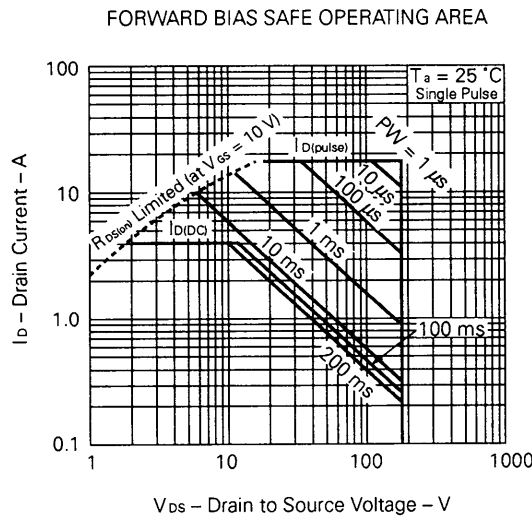
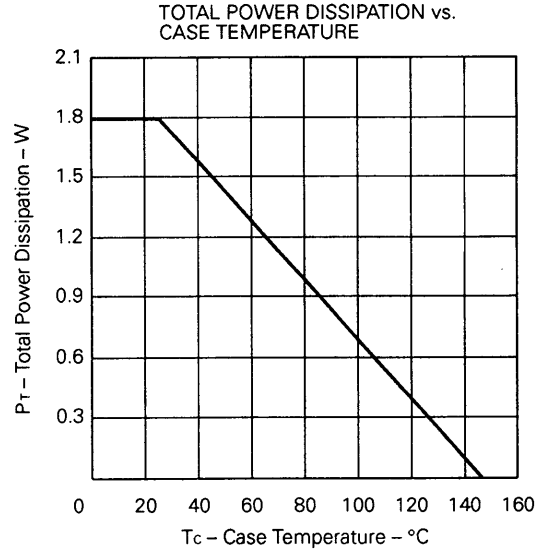
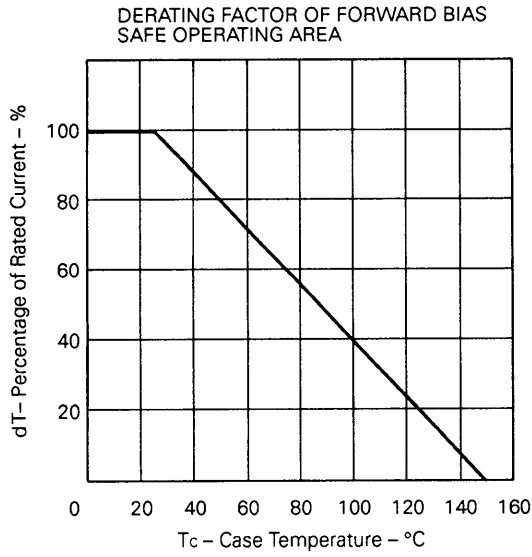
Radial Tape Specification



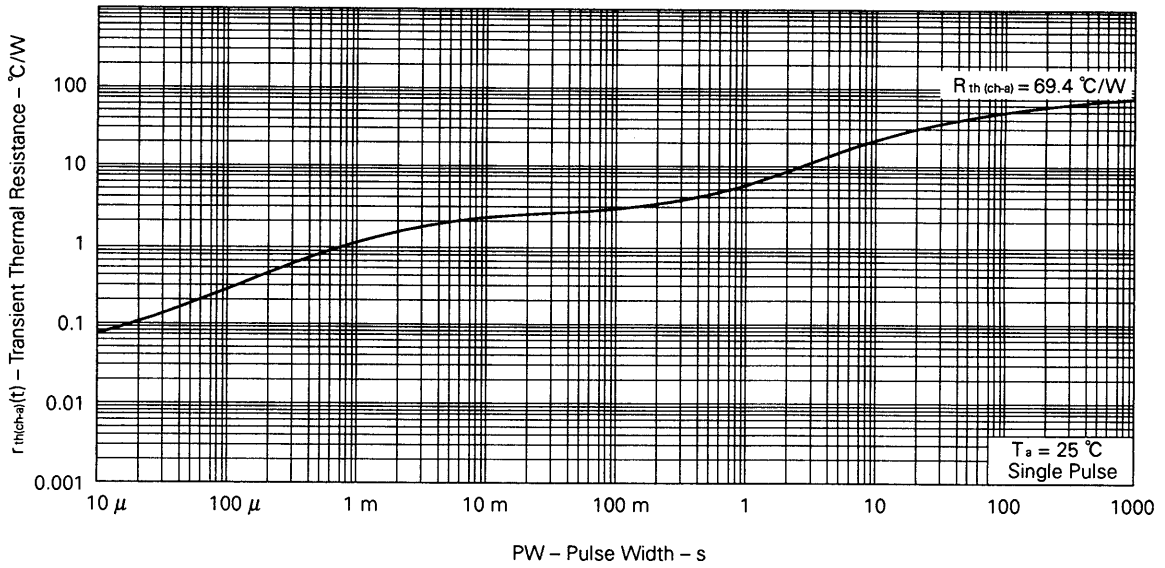
Dimension (unit : mm)

Item		
Component Body Length along Tape	$A_1$	$8.0 \pm 0.2$
Component Body Height	$A$	$13.0 \pm 0.2$
Component Body Width	$T$	$4.5 \pm 0.2$
Component Lead Width Dimension	$d$	$0.5 \pm 0.1$
Lead Wire Enclosure	$l_1$	2.5 MIN.
Component Center Pitch	$P$	$12.7 \pm 1.0$
Feedhole Pitch	$P_0$	$12.7 \pm 0.3$
Feedhole Center to Center Lead	$P_2$	$6.35 \pm 0.5$
Component Lead Pitch	$F_1, F_2$	$2.5 \begin{matrix} + 0.4 \\ - 0.1 \end{matrix}$
Deflection Front or Rear	$\Delta h$	$\pm 1.0$
Deflection Left or Right	$\Delta P$	$\pm 1.3$
Carrier Strip Width	$W$	$18.0 \begin{matrix} + 1.0 \\ - 0.5 \end{matrix}$
Adhesive Tape Width	$W_0$	5.0 MIN.
Feedhole Location	$W_1$	$9.0 \pm 0.5$
Adhesive Tape Position	$W_2$	0.7 MIN.
Height of Seating Plane	$H_0$	$16.0 \pm 0.5$
Feedhole to upper of Component	$H_1$	32.2 MAX.
Feedhole to Bottom of Component	$H$	20.0 MAX.
Tape Feedhole Diameter	$D_0$	$4.0 \pm 0.2$
Overall Taped Package Thickness	$t$	$0.7 \pm 0.2$

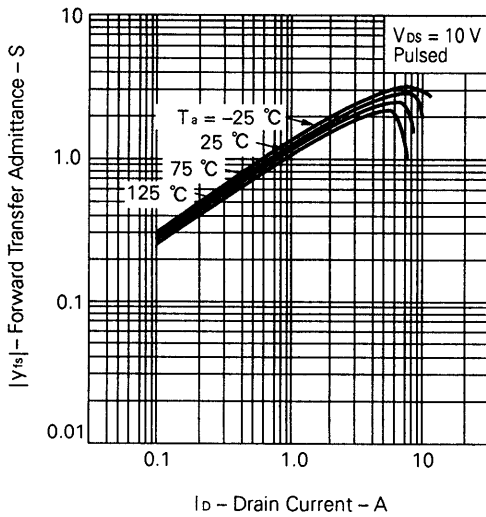
TYPICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)



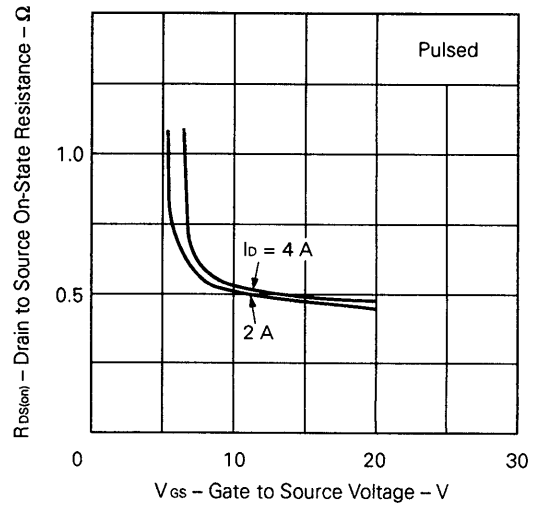
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



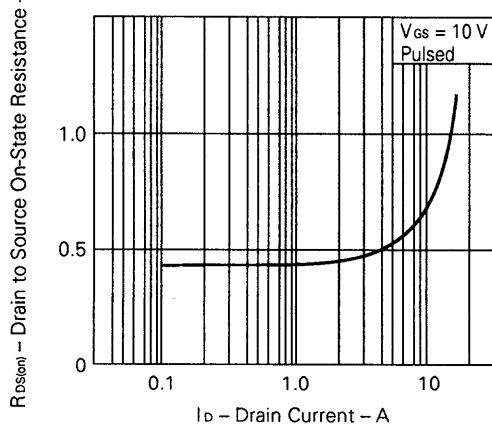
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



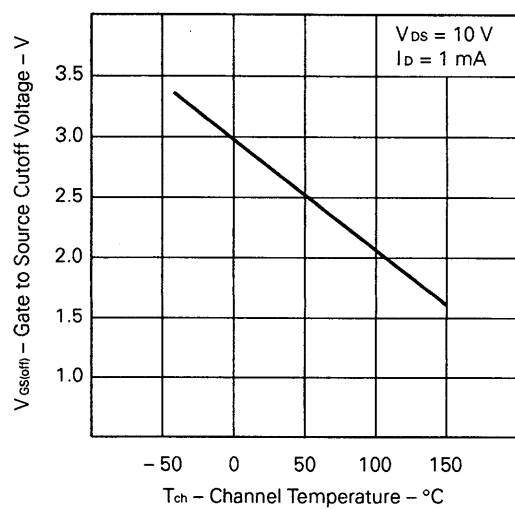
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



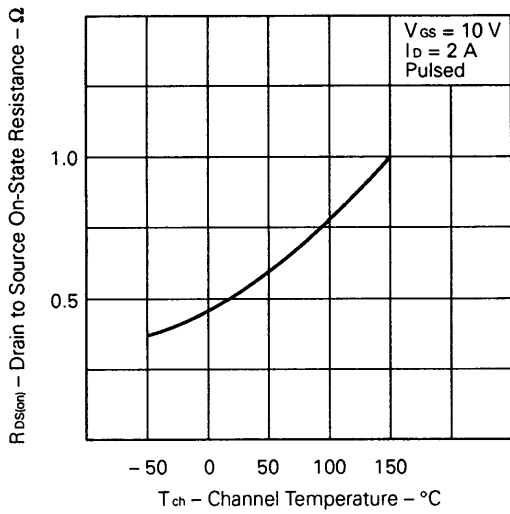
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



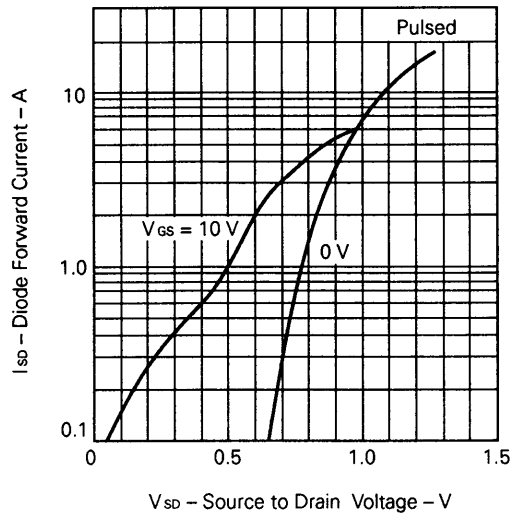
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE



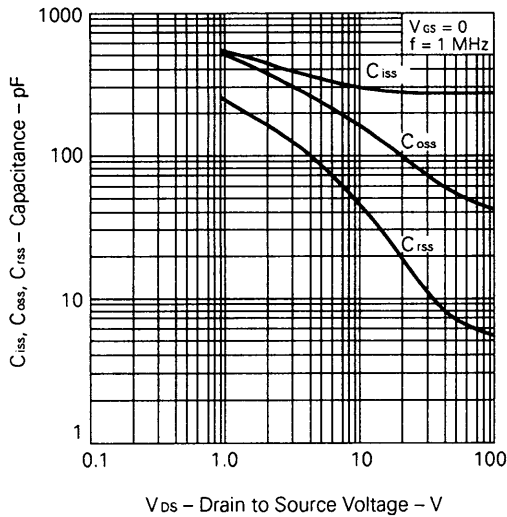
DRAIN TO SOURCE ON - STATE RESISTANCE vs. CHANNEL TEMPERATURE



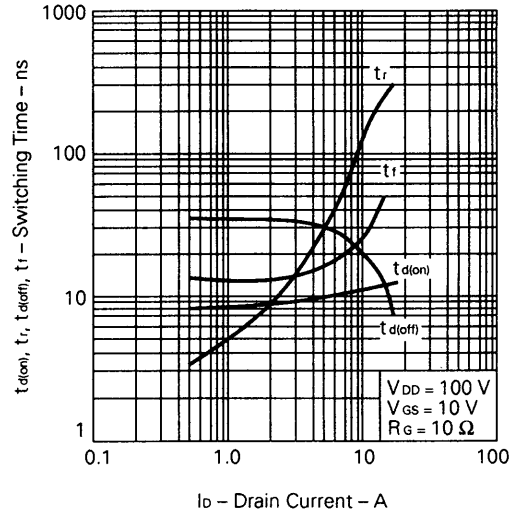
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



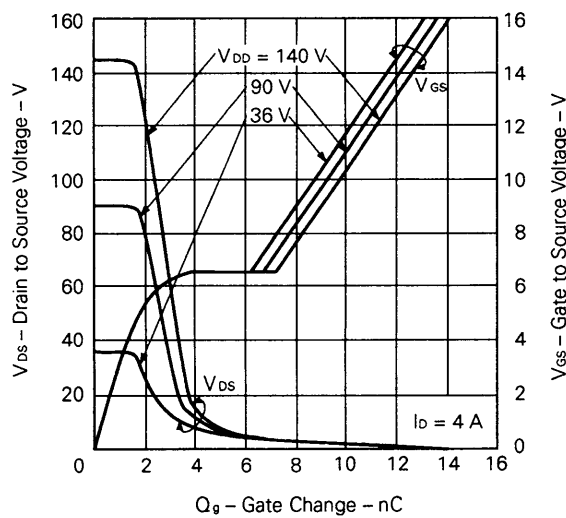
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



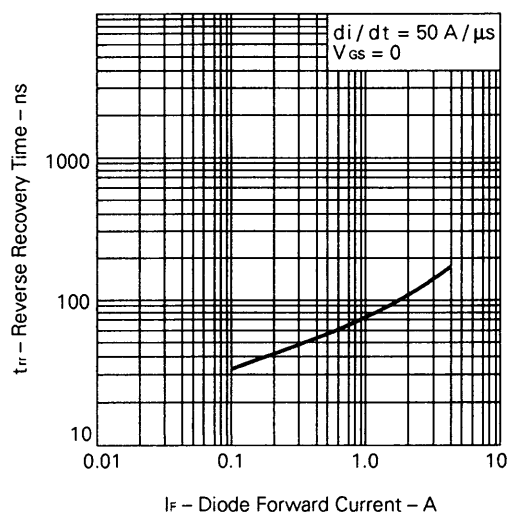
SWITCHING CHARACTERISTICS



DYNAMIC INPUT CHARACTERISTICS

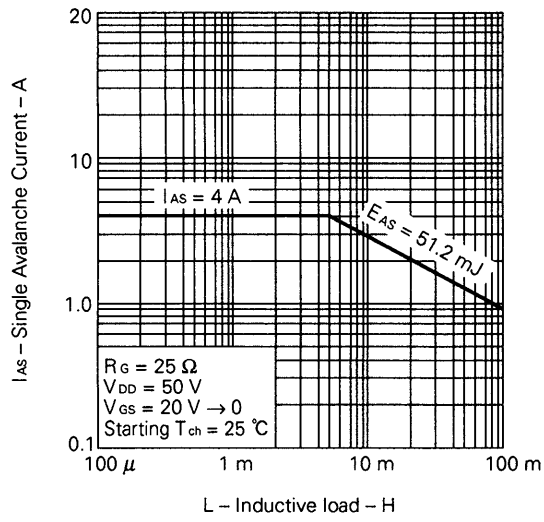


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

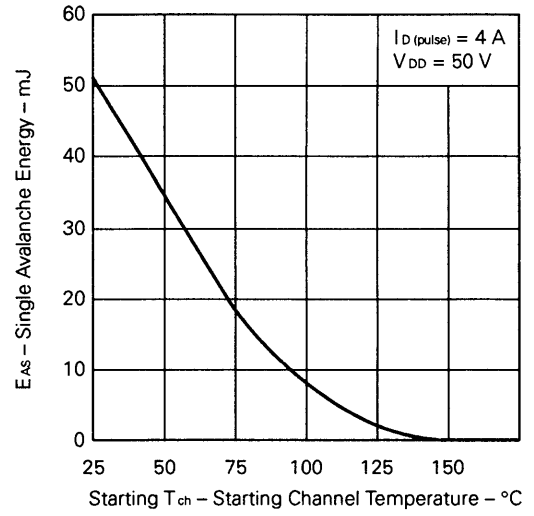




SINGLE AVALANCE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY vs. STARTING CHANNEL TEMPERATURE



[MEMO]

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